#### 39<sup>th</sup> ECPM

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## MICROWAVES TO PLASMA COUPLING TECHNIQUES ON THE AISHa SOURCE

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## Electron Cyclotron Resonance Ion Source



An absorption of the wave energy occurs when the electrons cross the surface where the magnetic field fulfilled the ECR condition



- ≻ long life-time
- ≻ low maintenance
- ≻ high stability
- ▹ intense CW or pulsed beams
- highly charged ions
- > gaseous and metallic elements





#### The possibility to operate with variable magnetic field allows the source performance to be optimized

\*S. Gammino and G. Ciavola, Plasma Source Sci. Technol, May 1996. 5, 19-27

 $B_{ECR}$ 

Waves in plasma:

- by external microwave generator
- Self-generated electrostatic oscillations

The propagation of e.m. waves is possible if  $\varepsilon > 0$ 

For cold plasma approximation  $(T_e = T_i \sim o)$ 

 $n_{cutoff} = 4\pi^2 \frac{m\epsilon_0}{\rho^2} f_p^2$ 

cut-off density

$$\mathcal{E}(\boldsymbol{\omega}) \approx 1 - \frac{\boldsymbol{\omega}_p^2}{\boldsymbol{\omega}^2}$$

$$\omega_p^2 = \frac{4\pi n_e e^2}{m_e}$$

plasma frequency



Above the cutoff the wave cannot propagate!

NFI

$$\bar{\bar{\varepsilon}} = \varepsilon_0 \bar{\bar{\varepsilon}}_r$$

$$\epsilon_{\gamma} = \begin{pmatrix} \epsilon_{xx} & \epsilon_{xy} & 0\\ \epsilon_{yx} & \epsilon_{yy} & 0\\ 0 & 0 & \epsilon_{zz} \end{pmatrix}$$



R wave



A resonance occurs when the direction of rotation of the plane of polarization of the wave is the same of the direction of the gyration of the electrons around the lines of the magnetic field



0.9

0.8

0.7

0.6

0.5

0.4

0.3

0.2

0.1



The plasma chamber is a **resonant cavity** for the electromagnetic waves

The heating and the ionization process change with the e.m. field distribution over the resonance surface

Only in proximity of high field the electron gained very high energies





Slight variation (~MHz) of the exciting frequency produces strong changes in the electric field distribution over the resonance surface, therefore on the ionization rate, and finally, on the output beam shape

## Frequency Tuning Effect (FTE)



NFN



If the electron are subject only the magnetostatic field it would escape from loss cones

The effect of the second frequency is to increase the electron temperature and improve the electron confinement

This means that also the ion confinement time increases and the extracted ion beam has higher charge states and currents

## Two Frequency Heating(TFH)





The electrons that leave the first ECR zone may be accelerated by the second one depending on the phase shift between the two waves









Chamber diameter	92 mm
Chamber length	357 mm
Operating Frequency	18 GHz
Operating Power (max)	1.5 kW
Extr Voltage (max)	40 kV
Weight	600 kg
Axial Magnetic Field	$(B_{INJ}/B_{MIN}/B_{EXT})$ 2.7 T/ 0.4 T / 1.6 T
Radial Magnetic Field	1.3 T

AISHa source was designed in order to adapt a high performance ECR ion source to hospital facilities needing multiply charged ion production with high reliability and brightness, easy operations and maintenance

Axial Confinement							
Helium-free superconducting	Axial Field	(INJ/MID/EXT) 2.6 T/ 0.4 T / 1.7 T					
interest in the second se	SC coil	INJ	Med1	Med2	Extr		
	ID (mm)	260	260	260	260		
	OD (mm)	340	340	340	340		
2°	Length (mm)	100	30	30	90		
2.5	Current (A/mm²)	165	143	143	115		
2 1.5			Ļ				
1	ECF	RISS	Standa	rd Mo	del		
		a	18 GF	1Z			
Z					ĮNFI		

#### **Radial Confinement**





#### 36 sgm Halbach-type Hexapole

inner radius 51 mm outer radius 110 mm length 400 mm VACODYM 745/677 HR Hcj =1.195×10<sup>3</sup> kA/m

9 directions of magnetization

# **1.3 T** on plasma chamber walls along whole length



#### **Injection System**





#### **Microwave Injection**

High Power Klystron Amplifiers RF1 [ 17.3 - 18.4 GHz ] RF2 [ 21 - 22 GHz ]



TFH

- multi-staged depressed collectors
- up to 2.4 kW output power
- 50 MHz of instantaneous bandwidth
- precise tuning of up to 24 channels
- Fast Digital Tuner System

chamber	φ=92 mm 1=357 mm
# modes	391
$\Delta f_{avg}$	~3 MHz

FTE



#### **Expected Currents**

	lon	Supernanogan (14 GHz)	AISHa (18 GHz + TFH)	
Au	H⁺	2000	4000	
(el	$H_2^+$	1200	2000	
on	H <sub>3</sub> +	1000	1500	
cti	<sup>3</sup> He⁺	800	2000	
gu	<sup>12</sup> C <sup>4+</sup>	250	800	
l	°Li <sup>2+</sup> - <sup>7</sup> Li <sup>2;</sup>	//	800	$\leq$
m	<sup>10</sup> B <sup>3+</sup> - 11⊳3+	//	600	
bea	1806+	400	1000	
uo	<sup>21</sup> Ne <sup>7+</sup>	120	500	
Ι	<sup>36</sup> Ar <sup>12+</sup>	20	150	

INFN

## AISHa - Conclusion

- Several *variation to the classical ECR-heating* mechanism have been proposed in order to increase the current and average charge state produced.
- The set of four superconducting coils independently energized will permit to realize a *flexible magnetic trap,* fundamental to study alternative heating schemes.
- The use of a *broadband microwave generator* will permit to efficiently tune the frequency improving the source performances.
- The injection system was designed in order to *optimize the microwave to plasma coupling* taking into account the need of space to house the *oven for metallic ion* beam production.



## Thanks for your attention!





## ECRIS Standard Model

>the radial magnetic field value at the plasma chamber wall must be B<sub>rad≥</sub>2B<sub>ECR</sub>;
>the axial magnetic field value at injection must be B<sub>inj</sub> ~3B<sub>ECR</sub> or more;
>the axial magnetic field value at extraction must be about B<sub>ext</sub>~B<sub>rad</sub>;
>the axial magnetic field value at minimum must be 0.30 <B<sub>min</sub>/B<sub>rad</sub>< 0.45.</li>
>the optimum power increases with the volume of the plasma and with the square of the frequency.

At power, magnetic fields and microwave frequencies used up to now obey to the Standard Model: the extracted current strongly increases as the microwave frequency increases, <u>but only the increase of mirror ratio can exploit</u> the performances, making effective the increase of electron density with frequency *High-B Mode* 

$$\bar{\bar{\varepsilon}} = \varepsilon_0 \bar{\bar{\varepsilon}}_r$$

$$\epsilon_{r} = \begin{pmatrix} \epsilon_{xx} & \epsilon_{xy} & 0\\ \epsilon_{yx} & \epsilon_{yy} & 0\\ 0 & 0 & \epsilon_{zz} \end{pmatrix}$$

k depends on the angle formed by the incoming wave with the magnetic field direction

There are two electromagnetic waves traveling in an arbitrary direction  $\theta$  with different propagation constants  $\vec{k_{\theta}}$  ordinary wave

 $k_{\theta}^{\prime\prime}$  extraordinary wave







NFM